MN4584B/MN4584BS

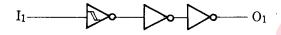
Hex Schmitt Trigger

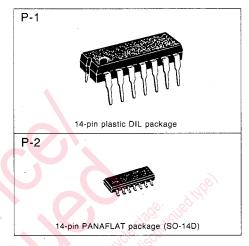
■ Outline

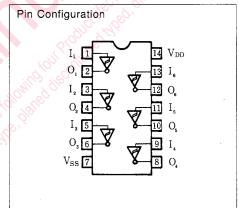
The MN4584B/S has six built-in waveform shaping circuits. It is suitable for application to which low power consumption and high noise immunity are essential, and suitable especially for application to a waveform shaping circuit using such inputs whose rise and fall are rather slow.

This hex Schmitt trigger is equivalent to Motorola's MC14584B.

■ Logic Diagram







■ Absolute Maximum Ratings (Ta=25°C)

Supply voltage Input voltage		Symbol	Rating	Unit V	
		$V_{ m DD}$	-0.5~+18		
		VI	$-0.5 \sim V_{DD} + 0.5 *$	V	
Output pin voltage		Vo	$-0.5 \sim V_{DD} + 0.5^*$	V	
Peak input · output pin current		$\pm I_{I}$	max. 10	mA	
Power dissipation Ta=-40~+60°C		D	max. 400	mW	
(per package)	Ta=+60~+80°C	P_{D}	Decrease to 200mW at the rate of 8mW/°C	11177	
Power dissipation (per output pin)		P_D	max. 100	mW	
Operating ambient temperature		T_{opr}	-40~+85	°C	
Storage temperature		$T_{\rm stg}$	-65~+150	°C	

^{*} $V_{DD}+0.5V$ should be lower than 18V.

■ DC Characteristics (V_{SS}=0V)

Item	V_{DD}	Symbol	Symbol Condition		Ta=-40°C		Ta=25°C		Ta=85°C		Unit
	(V)	Cymbon		min.	max.	min.	max.	min.	max.	Unit	
0	5	_			_	1		1		7.5	
Static supply current	10	I _{DD}	$V_I = V_{SS}$ or	$V_{ m DD}$		2	—	2	_	15	μΑ
	15	ļ				. 4		4		30	
	5	İ	V ₁ =V _{ec} or	$V_1 = V_{SS}$ or V_{DD}		0.05	_	0.05	_	0.05	
Output voltage low level	10	V_{OL}	$ I_0 < 1\mu A$		_	0.05		0.05	 	0.05	V
	15		11(): < 1 μω: 1			0.05	_	0.05		0.05	
•	5		VV or	V	4.95	_	4.95	_	4.95		
Output voltage high level	10	V _{OH}	$V_1 = V_{SS}$ or V_{DD}		9.95		9.95		9.95	_	V
	15		Io<1μA		14.95		14.95		14.95		
Input voltage low level	5			$V_0 = 0.5V$ or 4.5V	_	1.5		1.5		1.5	
	10	VIL	I ₀ <1μΑ	V ₀ =1V or 9V		3	_	3		3	V
	15			$V_0 = 1.5V$ or $13.5V$)	4		4		4	
	5			V ₀ =0.5V or 4.5V	3.5		3.5		3.5		
Input voltage high level	10	V_{IH}	$ I_0 < 1\mu A$	$V_0=1V \text{ or } 9V$	7	-	7		7	-	V
	15			$V_0 = 1.5V$ or $13.5V$	11		11		11	12	
	5		$V_0 = 0.4V$,	$V_i=0 \text{ or } 5V$	0.52	7-1	0.44	-06	0.36	_	
Output current low level	10	I_{OL}	$V_0 = 0.5V$, $V_1 = 0$ or $10V$		1.3		1.1	700	0.9		mA
	15	<u></u>	$V_0 = 1.5V$, $V_1 = 0$ or 15V		3.6	_	3,0	ک سر 2	2.4		
	5		$V_0 = 4.6V$,	$V_i = 0$ or $5V$	0.52		0.44	9,	0.36		
Output current high level	10	-I _{OH}	V_0 =9.5V, V_1 =0 or 10V V_0 =13.5V, V_1 =0 or 15V		1.3	 č	1.15	~	0.9		mA
	15				3.6	, <u>d</u>	3		2.4	_	
Output current high level	5	$-I_{OH}$	$V_0 = 2.5V$,	1.7	1000	1.4		1.1		mA	
Input leakage current	15	$\pm I_i$	$V_I=0$ or 15	×500	0.3		0.3		1	μΑ	

■ Switching Characteristics (Ta=25°C, V_{ss}=0V, C_L=50pF)

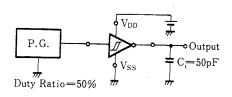
Item	$V_{DD}(V)$	Symbol	min.	typ.	max.	Unit
	5	1001	416-	60	180	***
Output rise time (Fig. 1)	10	trli	<u>.</u>	30	90	ns
	15	THE COLLEGE	_	20	60	
	5	Colle Mille	_	60	180	
Output fall time	10	t _{THL}		30	90	ns
	15	10°,		20	60	
	5		_	75	225	
Propagation time (Fig. 1)	10	t _{PLH}		35	105	ns
	15			30	90	
	(⁽²⁾ 5		_	90	270	
Propagation time (Fig. 1)	10	t _{PHL}		35	105	ns
	15		_	30	90	
	5			3.0	3.5	
Threshold voltage (Fig. 2)	10	V_{IH}	_	5.8	7	V
	15			8.3	11	

Item	$V_{DD}(V)$	Symbol	min.	typ.	max.	Unit
Threshold voltage (Fig. 2)	5		1.5	2.2		
	10	V _{IL}	3	4.5		V
	15		4	6.5	_	
Hysteresis voltage (Fig. 2)	5	· V _H	0.5	0.8		<u> </u>
	10		0.7	1.3		V
	15		0.9	1.8	_	
Input capacitance		Cı	_	_	7.5	pF

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Fig. 1 Switching time measuirng circuit and waveforms

1. Switching time measuring circuit



2. Switching waveforms

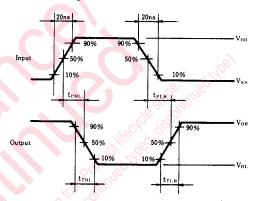
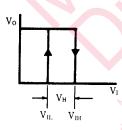
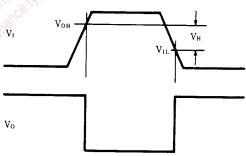


Fig. 2 Input-output characteristics



Transfer characteristics



Above waveform specifies $V_{tH},\ V_{tL}$ and V_{tL} and V_{tH} are in the scope from 30% to 70%.

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